

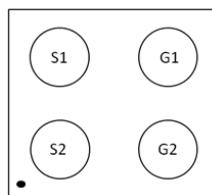
Product Summary

V _{SS}	R _{SS(ON)} Max	I _S T _A = +25°C
24V	45mΩ @ V _{GS} = 4.5V	1.6A

Description and Applications

This new generation MOSFET is designed to minimize the on-state resistance (R_{SS(ON)}) and making it ideal for high efficiency power management.

- Battery Management
- Load Switch
- Battery Protection



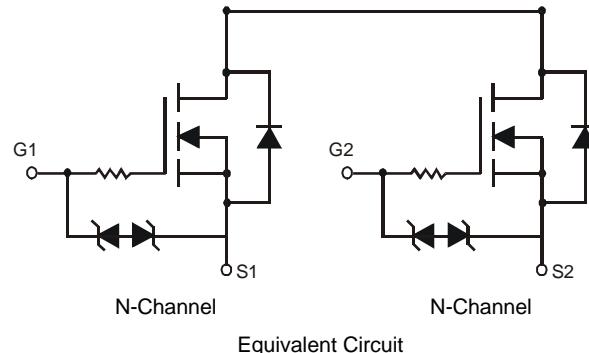
Top View

Features and Benefits

- Built-in G-S Protection Diode against ESD 2kV HBM
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

Mechanical Data

- Case: X2-WLB1616-4
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminal Material: SnAgCu Ball
- Weight: 0.0023 grams (Approximate)



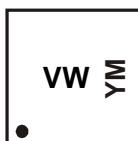
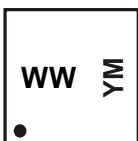
Ordering Information (Note 4)

Part Number	Case	Packaging
DMN2036UCB4-7	X2-WLB1616-4	3000/Tape & Reel

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



VW/VW = Product Type Marking Code
 YM = Date Code Marking
 Y = Year (ex: E = 2017)
 M = Month (ex: 9 = September)

Date Code Key

Year	2015	2016	2017	2018	2019	2020	2021					
Code	C	D	E	F	G	H	I					
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Maximum Ratings

Characteristic			Symbol	Value	Unit
Source-Source Voltage			V _{SSS}	24	V
Gate-Source Voltage			V _{GSS}	±12	V
Continuous Source Current @ T _A = +25°C (Note 5)	Steady State	T _A = +25°C T _A = +70°C	I _S	1.6 1.3	A
Pulsed Source Current @ T _A = +25°C (Notes 5 & 6)			I _{SM}	30	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation, @T _A = +25°C (Note 5)	P _D	1.45	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 5)	R _{θJA}	86.68	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Source to Source Breakdown Voltage T _J = +25°C	V _{(BR)SS}	24	—	—	V	I _S = 1mA, V _{GS} = 0V
Zero Gate Voltage Source Current T _J = +25°C	I _{SSS}	—	—	1.0	μA	V _{SS} = 20V, V _{GS} = 0V
Gate-Body Leakage	I _{GSS}	—	—	±10	μA	V _{GS} = ±8V, V _{SS} = 0V
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(TH)}	0.5	—	1.3	V	V _{SS} = 10V, I _S = 1.0mA
Static Source-Source On-Resistance	R _{SS(ON)}	20 20.5 21 22 23	29 30 31 33 36	45 48 50 57 72	mΩ	V _{GS} = 4.5V, I _S = 3.0A V _{GS} = 4.0V, I _S = 3.0A V _{GS} = 3.7V, I _S = 3.0A V _{GS} = 3.1V, I _S = 3.0A V _{GS} = 2.5V, I _S = 3.0A
Forward Transfer Admittance	Y _{fs}	—	9.4	—	S	V _{SS} = 10V, I _S = 3.0A
Body Diode Forward Voltage	V _{F(S-S)}	—	0.8	1.2	V	I _F = 3.0A, V _{GS} = 0V
DYNAMIC CHARACTERISTICS (Note 8)						
Total Gate Charge	Q _g	—	12.6	—	nC	V _{GS} = 4.5V, V _{SS} = 10V, I _S = 6A
Turn-On Delay Time	t _{D(ON)}	—	183	—	ns	V _{DD} = 10V, R _L = 3.33Ω, I _S = 3.0A
Turn-On Rise Time	t _R	—	278	—	ns	
Turn-Off Delay Time	t _{D(OFF)}	—	738	—	ns	
Turn-Off Fall Time	t _F	—	572	—	ns	

Notes:

- 5. Device mounted on FR-4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu.
- 6. Repetitive rating, pulse width limited by junction temperature.
- 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to production testing.

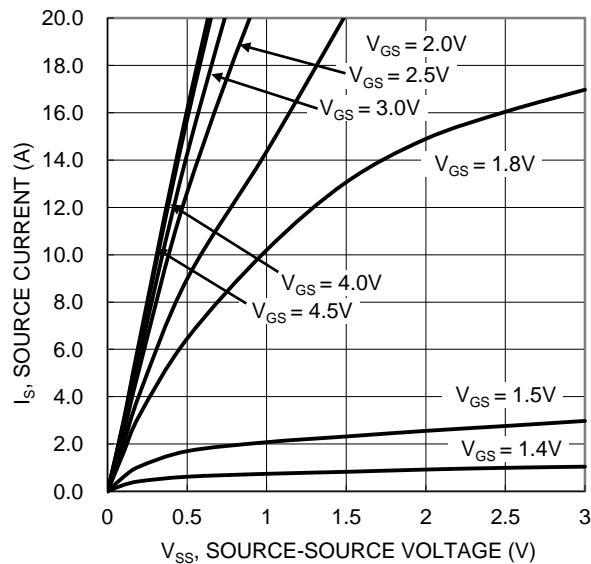


Figure 1. Typical Output Characteristic

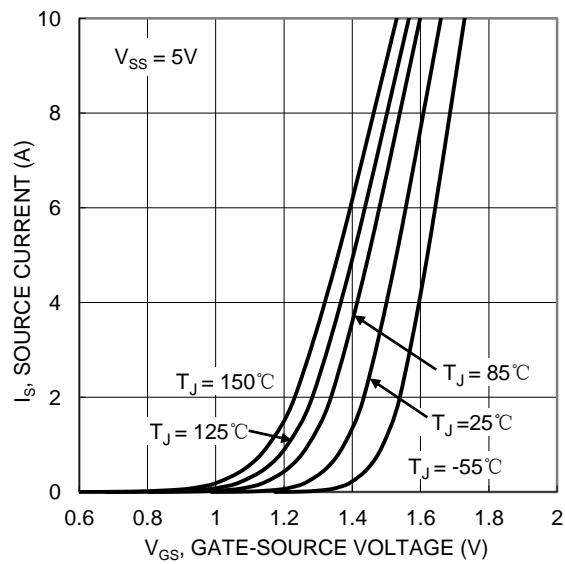


Figure 2. Typical Transfer Characteristic

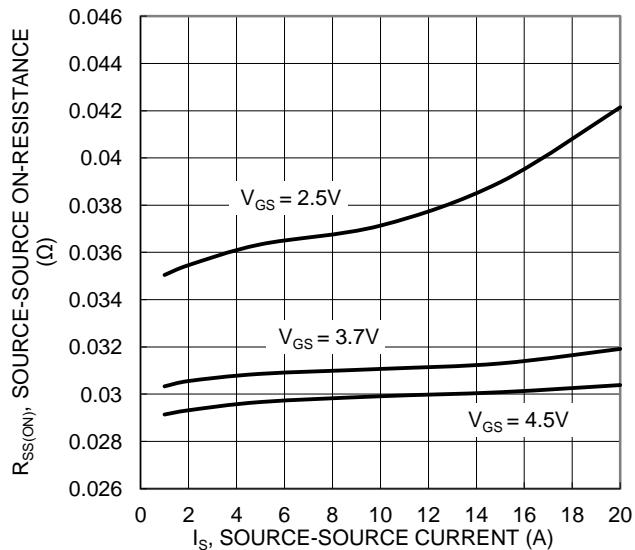


Figure 3. Typical On-Resistance vs. Source Current and Gate Voltage

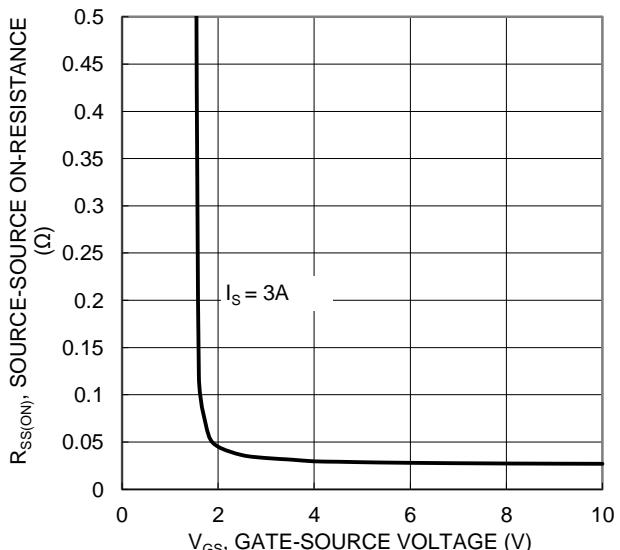


Figure 4. Typical Transfer Characteristic

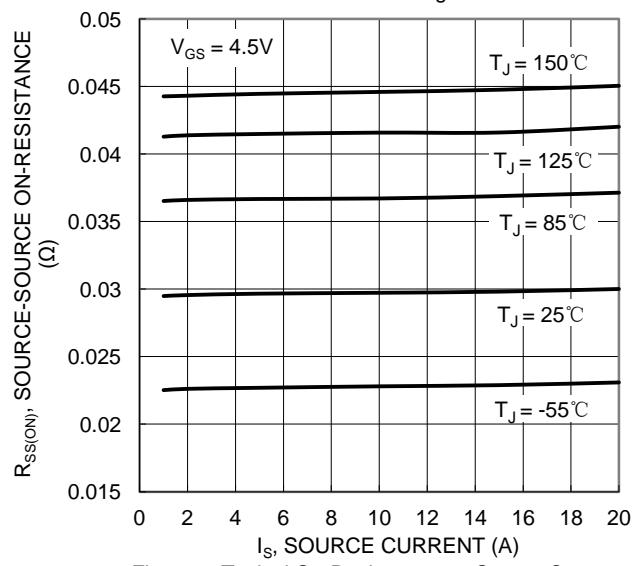


Figure 5. Typical On-Resistance vs. Source Current and Junction Temperature

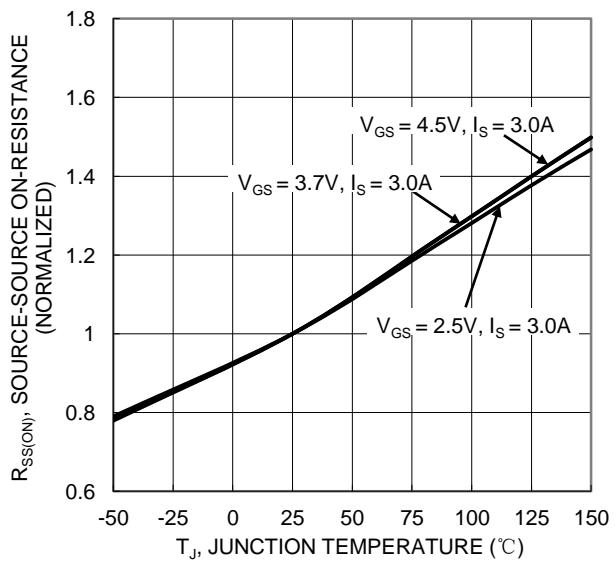


Figure 6. On-Resistance Variation with Junction Temperature

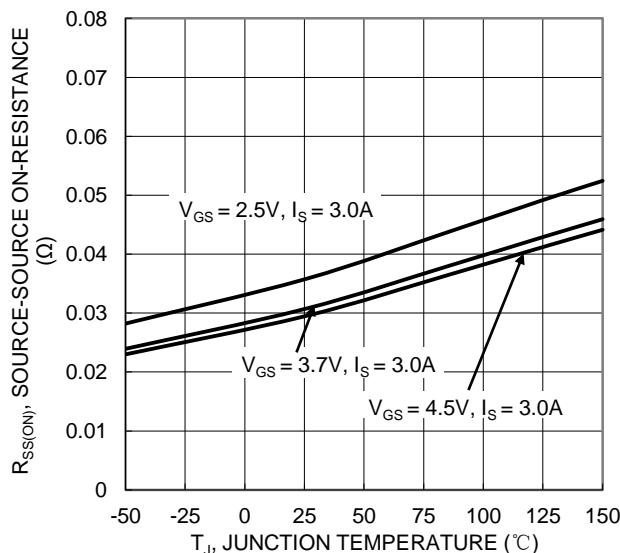


Figure 7. On-Resistance Variation with Junction Temperature

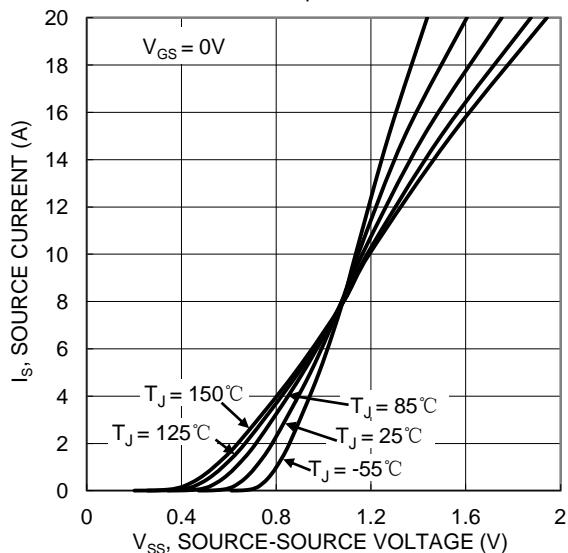


Figure 9. Diode Forward Voltage vs. Current

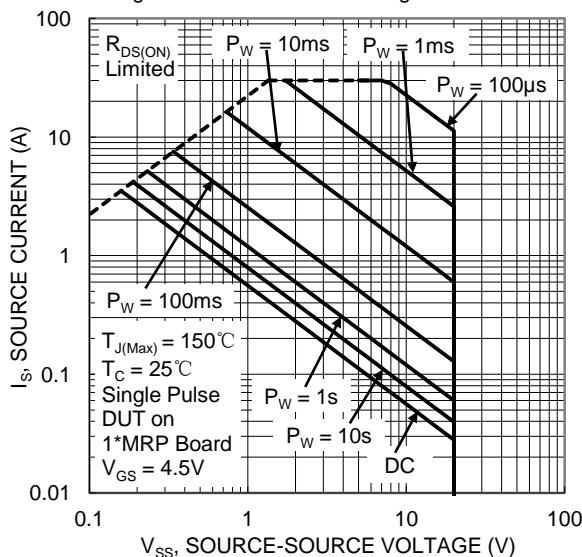


Figure 11. SOA, Safe Operation Area

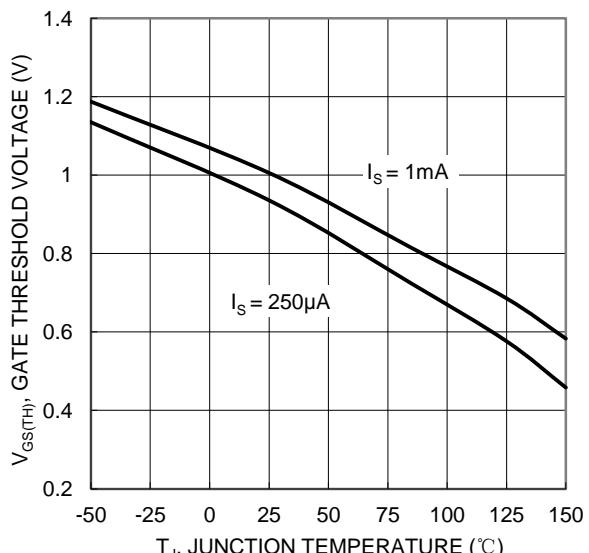


Figure 8. Gate Threshold Variation vs. Junction Temperature

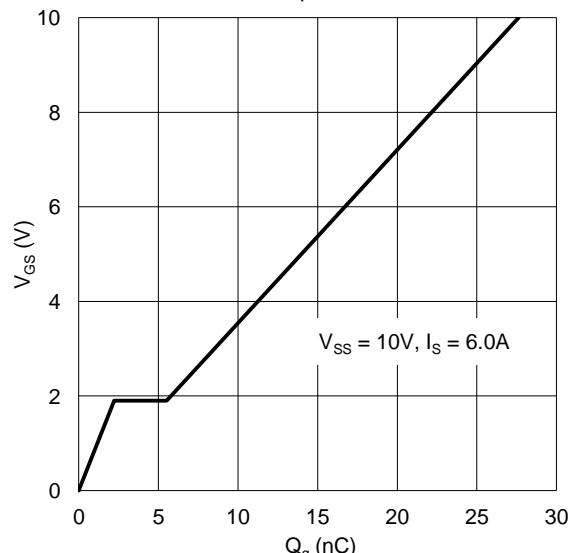


Figure 10. Gate Charge

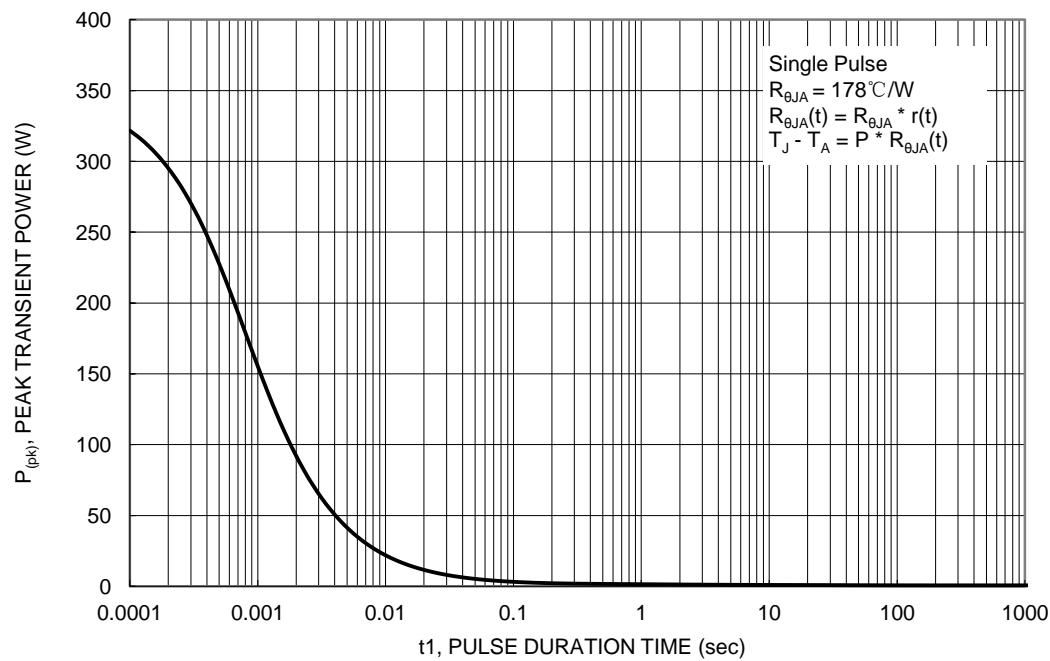


Figure 12. Single Pulse Maximum Power Dissipation

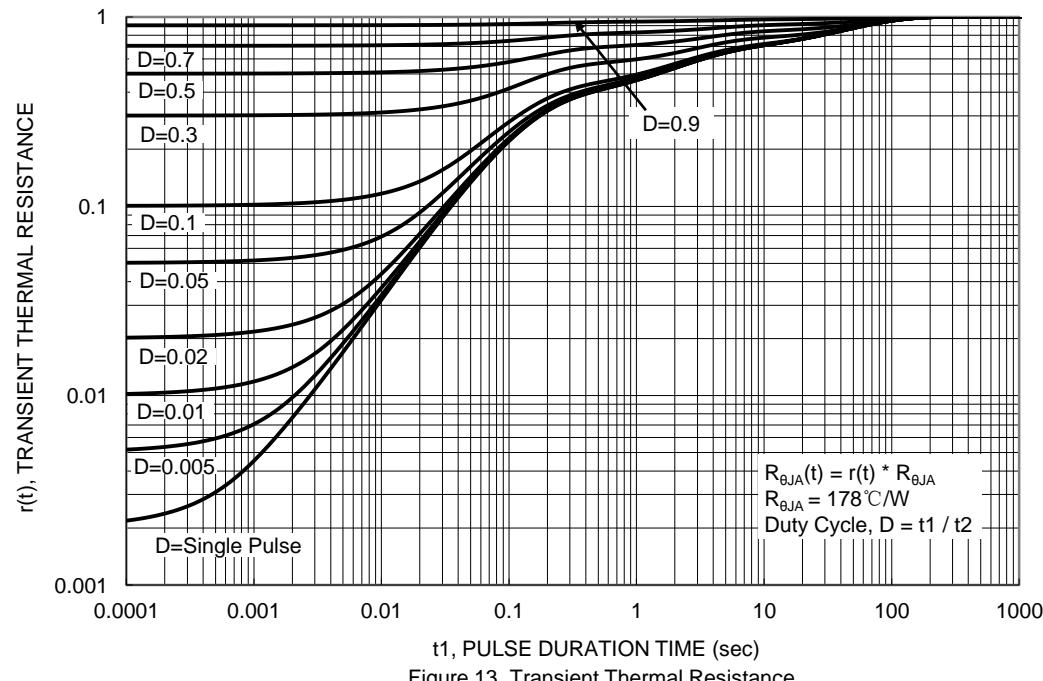
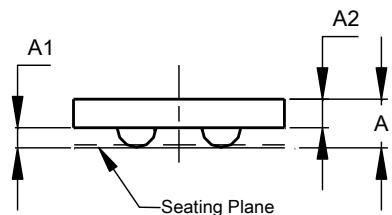
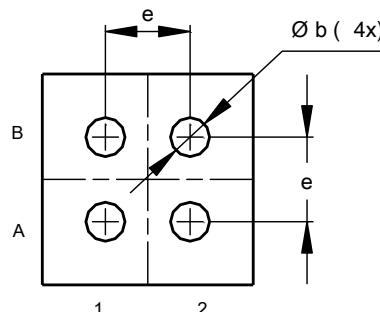
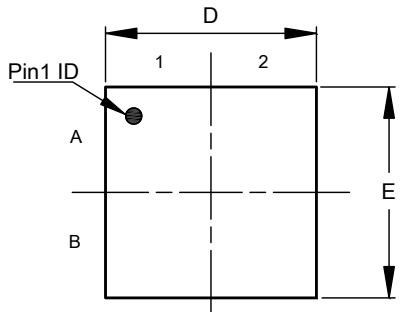


Figure 13. Transient Thermal Resistance

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

X2-WLB1616-4



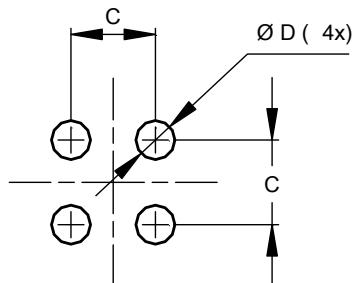
X2-WLB1616-4			
Dim	Min	Max	Typ
A	--	0.40	0.37
A1	--	--	0.15
A2	--	--	0.22
b	0.25	0.35	0.30
D	1.58	1.66	1.62
E	1.58	1.66	1.62
e	-	-	0.65

All Dimensions in mm

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

X2-WLB1616-4



Dimensions	Value (in mm)
C	0.65
D	0.30

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